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PHOTOMULTIPLIER TUBES R8486, R8487

For Vacuum Ultraviolet Light Detection Cs-Te (R8486), Cs-I (R8487) Photocathode, MgF2 Window, 28 mm (1-1/8 Inch) Diameter, 9-stage, Side-on Type

FEATURES

 Sensitivity in the Vacuum Ultraviolet Region R8486.....115 to 320 nm R8487......115 to 195 nm High Quantum Efficiency (at 121.6 nm) R8486......22.5 % (Typ.) R8487.....26.0 % (Typ.) High Anode Sensitivity R8486 (at 254 nm)......5.2 \times 10⁵ A/W (Typ.) R8487 (at 121.6 nm)......1.0 \times 10⁵ A/W (Typ.)



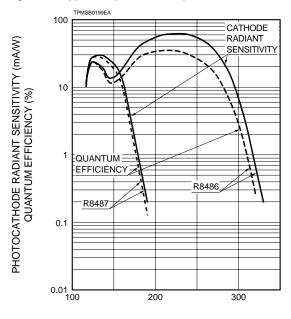
APPLICATIONS

Emission Spectroscopy, etc.

GENERAL

Pai	rameter	R8486	R8487	Unit		
Spectral Respo	onse	115 to 320	115 to 320 115 to 195			
Wavelength		200	130	nm		
of Maximum R	esponse	200	130	11111		
Photocathode	Material	Cs-Te	Cs-I	_		
Window Mater	ial	Mg	_			
Minimum Effect	ctive Area	8×	mm			
Dynode	Structure	ir-cage	_			
	Number of Stage	(_			
	Material	Sb-	_			
Direct	Anode to Dynode No.9	Appr	pF			
Interelectrode	Anode to	Appr	pF			
Capacitances	All Other Electrodes	Аррі	ы			
Base		11-pin base JED	_			
Weight		4	g			
Suitable Socke	et for Base (option)	E678	_			

Figure 1: Typical Spectral Response



WAVELENGTH (nm)

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MAXIMUM RATINGS (Absolute Maximum Values)

Parameter	Rating	Unit		
Supply Voltage				
Between Anode and Cathode	1250	V dc		
Between Anode and Last Dynode	250	V dc		
Between Successive Dynodes	250	V dc		
Between First Dynode and Cathode	250	V dc		
Average Anode Current (A)	0.1	V dc		
Ambient Temperature	-30 to +50	°C		

CHARACTERISTICS (at 25 °C)

Parameter	R8486	R8487	Unit	
Cathode Sensitivity				
Quantum Efficiency at 121 nm	22.5	26.0	%	
at 254 nm	25.0	_	%	
Anode Sensitivity ®				
Radiant at 121 nm	_	1.0 × 10 ⁵	A/W	
at 254 nm	5.2 × 10 ⁵	_	A/W	
Gain	1.0 × 10 ⁷	3.9 × 10 ⁶	_	
Anode Dark Current (After 30 minute storage in darkness) ©	1.0	0.1	nA	
ENI (Equivalent Noise Input) [®] at 121 nm	-	1.12 × 10 ⁻¹⁶	W	
at 254 nm	1.09 × 10 ⁻¹⁶	_	W	
Time Response				
Anode Pulse Rise Time ©	2.2	2.2	ns	
Electron Transit Time [©]	22	22	ns	
Transit Time Spread [©]	1.2	1.2	ns	

NOTES

- A: Averaged over any interval of 30 seconds maximum.
- B: Measured with the same light source as Note B and with the voltage distribution ratio shown in Table 1 below.

Table 1: Voltage Distribution Ratio

Electrode	к	Dу	1 D	y2	Dy3	Dy∠	ı D	y5	Dy6	Dy7	D;	y8	Dy9	F)
Distribution Ratio		1	1	1		1	1	1		1	1	1	1	1	

Supply Voltage=1000 V dc

K: Cathode Dy: Dynode P: Anode

- ©: Measured with the same supply voltage and voltage distribution ratio as Note E after removal of light.
- D: ENI is an indication of the photon-limited signal-to-noise ratio. It refers to the amount of light in watts to produce a signal-to-noise ratio of unity in the output of a photomultiplier tube.

$$ENI = \frac{\sqrt{2q \cdot ldb \cdot G \cdot \Delta f}}{s}$$

where $q = Electronic charge (1.60 \times 10^{-19} coulomb)$.

ldb = Anode dark current(after 30 minutes storage) in amperes.

G = Gain.

- Δf = Bandwidth of the system in hertz. 1 hertz is used.
- S = Anode radiant sensitivity in amperes per watt at the wavelength of peak response.

- E: The rise time is the time for the output pulse to rise from 10 % to 90 % of the peak amplitude when the entire photocathode is illuminated by a delta function light pulse.
- E: The electron transit time is the interval between the arrival of delta function light pulse at the entrance window of the tube and the time when the anode output reaches the peak amplitude. In measurement, the whole photocathode is illuminated.
- ©: Also called transit time jitter. This is the fluctuation in electron transit time between individual pulses in the signal photoelectron mode, and may be defined as the FWHM of the frequency distribution of electron transit times.

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Figure 2: Typical Gain and Anode Radiant Sensitivity

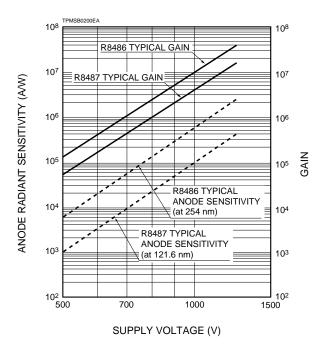


Figure 3: Typical Time Response

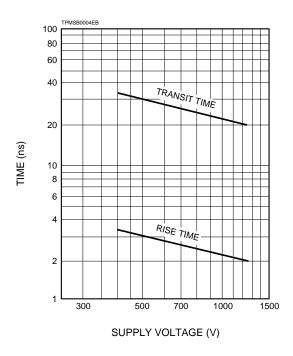


Figure 4: Dimensional Outline and Basing Diagram (Unit: mm)

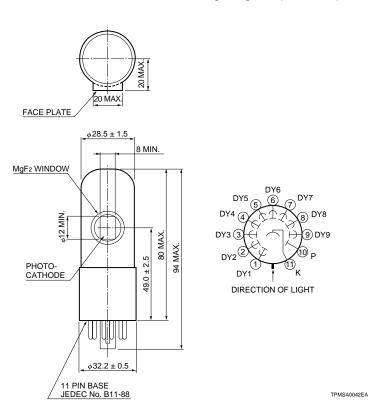
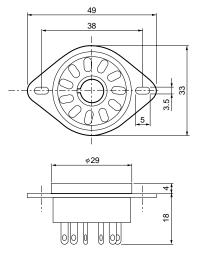


Figure 5: Socket E678-11A (Option) (Unit: mm)



TACCA0064EA

NOTE: There is a 2 mm diameter hole to exhaust inner air on the plastic base.

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Warning—Personal Safety Hazards

Electrical Shock—Operating voltages applies to this device present a shock hazard.

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HAMAMATSU PHOTONICS K.K., Electron Tube Center

314-5, Shimokanzo, Toyooka-village, Iwata-gun, Shizuoka-ken, 438-0193, Japan, Telephone: (81)539/62-5248, Fax: (81)539/62-2205

U.S.A.: Hamamatsu Corporation: 360 Foothill Road, P. O. Box 6910, Bridgewater. N.J. 08807-0910, U.S.A., Telephone: (1)908-231-0960, Fax: (1)908-231-1218 E-mail: usa@hamamatsu.com
Germany: Hamamatsu Photonics Deutschland GmbH: Arzbergerstr. 10, D-82211 Herrsching am Ammersee, Germany, Telephone: (49)8152-375-0, Fax: (49)8152-2658 E-mail: info@hamamatsu.de
France: Hamamatsu Photonics France S.A.R.L.: 8, Rue du Saule Trapu, Parc du Moulin de Massy, 91882 Massy Cedex, France; Telephone: (34) 69 53 71 00, Fax: (33)16 65 37 100. F-mail: info@hamamatsu.co.uk
United Kingdom: Hamamatsu Photonics UK Limited: 2 Howard Court, 10 Tewin Road Welwyn Garden City Hertfordshire AL7 1BW, United Kingdom, Telephone: 44-(0)1707-294888, Fax: 44(0)1707-325777 E-mail: info@hamamatsu.co.uk North Europe: Hamamatsu Photonics Norden AB: Smidesvägen 12, SE-171-41 SOLNÁ, Sweden, Telephone: (46)8-509-031-00, Fax: (46)8-509-031-01 E-mail: info@hamamatsu.se Italy: Hamamatsu Photonics Italia: S.R.L.: Strada della Moia, 1/E, 20020 Arese, (Milano), Italy, Telephone: (39)02-935 81 733, Fax: (39)02-935 81 741 E-mail: info@hamamatsu.it TPMS1070E01 FEB. 2001 IP Printed in Japan (1,000)